

III B.Tech I Semester Regular Examinations, November 2007

DIGITAL IC APPLICATIONS

(Common to Electronics & Communication Engineering and Electronics & Instrumentation Engineering)

Time: 3 hours

Max Marks: 80

Answer any FIVE Questions
All Questions carry equal marks

1. (a) Explain how to estimate sinking current for low output and sourcing current for high output of CMOS gate.
- (b) Analyze the fall time of CMOS inverter output with $R_L = 100\Omega$, $V_L = 2.5V$ and $C_L = 10PF$. Assume V_L as stable state voltage. [8+8]
2. (a) Draw the circuit diagram of basic TTL NAND gate and explain the three parts with the help of functional operation.
- (b) Explain sinking current and sourcing current of TTL output. Which of the above parameters decide the fan-out and how? [8+8]
3. (a) Write a VHDL Entity and Architecture for the following function?

$$F(x) = a \oplus b \oplus c$$

Also draw the relevant logic diagram.

- (b) Explain the use of Packages Give the syntax and structure of a package in VHDL [8+8]
4. Design the logic circuit and write a data-flow style VHDL program for the following functions.
 - (a) $F(X) = \Sigma_{A,B,C,D} (0, 2, 5, 7, 8, 10, 13, 15) + d(1, 6, 11)$
 - (b) $F(Y) = \Pi_{A,B,C,D} (1, 4, 5, 7, 9, 11, 12, 13, 15)$ [8+8]
5. With the help of logic diagram explain 74×157 multiplexer? Write the data flow style VHDL program for this IC? [16]
6. Design a 24-bit comparator circuit using 74×682 ICs and discuss the functionality of the circuit. Also implement VHDL source code in data flow style. [16]
7. (a) Distinguish between latch and flip-flop. Show the logic diagram for both. Explain the operation with the help of function table.
- (b) Design a Modulo-12 ripple counter using 74×74? Write a VHDL program for this logic using data flow style. [8+8]
8. (a) Discuss how PROM, EPROM and EEPROM technologies differ from each other.

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Set No. 2

- (b) With the help of timing waveforms, explain read and write operations of SRAM. [8+8]
